

Bias Resistor Transistor

PNP Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

- Applications

Inverter, Interface, Driver

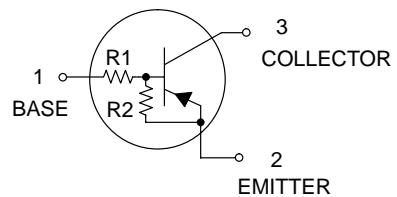
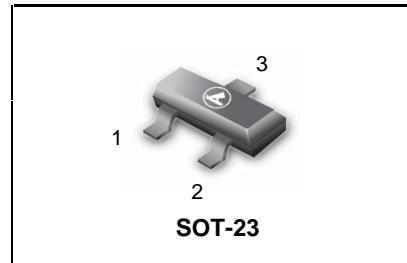
- Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
 - 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
 - 3) Only the on / off conditions need to be set for operation, making the device design easy.
- We declare that the material of product compliance with RoHS requirements.
 - S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits		Unit
Supply voltage	Vcc	-50		V
Input voltage	V _{IN}	-12 to +5		V
Output current	I _c	-500		mA
Power dissipation	P _D	200		mW
Junction temperature	T _j	150		°C
Storage temperature	T _{stg}	-55 to +150		°C

LDTB123YLT1G
S-LDTB123YLT1G



DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTB123YLT1G S-LDTB123YLT1G	F52	2.2	10	3000/Tape & Reel
LDTB123YLT3G S-LDTB123YLT3G	F52	2.2	10	10000/Tape & Reel

● Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V _{i(off)}	—	—	-0.3	V	V _{cc} =-5V, I _o =-100μA
	V _{i(on)}	-2	—	—		V _o =-0.3V, I _o =-20mA
Output voltage	V _{o(on)}	—	-0.1	-0.3	V	I _o /I _l =-50mA/-2.5mA
Input current	I _i	—	—	-3.0	mA	V _i =-5V
Output current	I _{o(off)}	—	—	-0.5	μA	V _{cc} =-50V, V _i =0V
DC current gain	G _i	56	—	—	—	V _{cc} =-5V, I _o =-50mA
Input resistance	R _i	1.54	2.2	2.86	kΩ	—
Resistance ratio	R ₂ /R ₁	3.6	4.5	5.5	—	—
Transition frequency	f _t	—	200	—	MHz	V _{ce} =-10V, I _e =50mA, f=100MHz *

* Transition frequency of the device

LDTB123YLT1G, S-LDTB123YLT1G

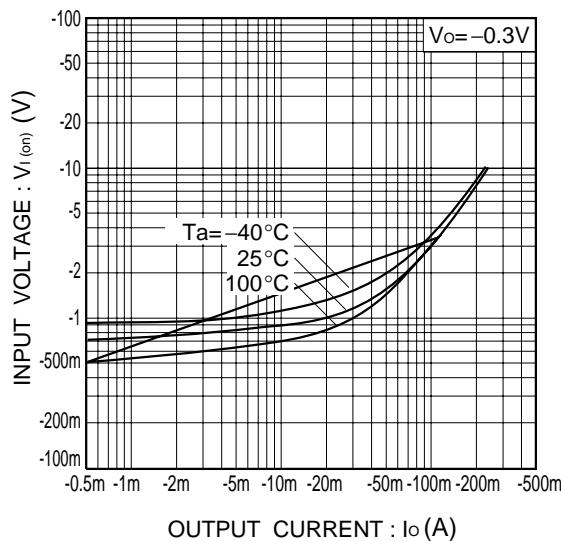
● **Electrical characteristic curves**


Fig.1 Input voltage vs. output current
(ON characteristics)

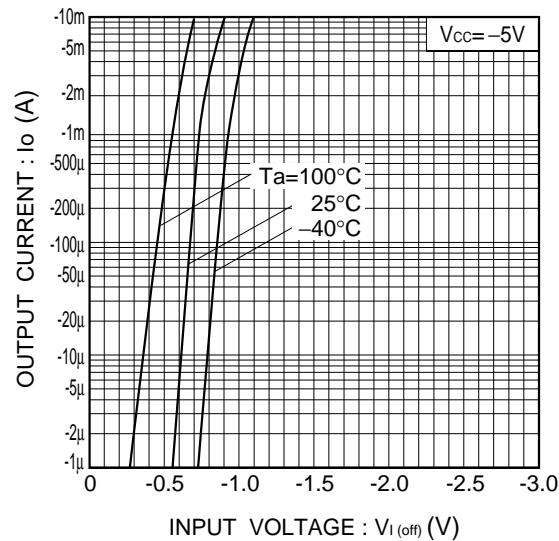


Fig.2 Output current vs. input voltage
(OFF characteristics)

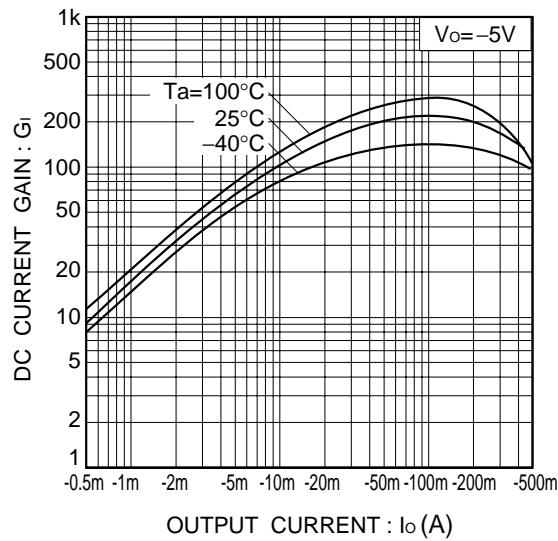


Fig.3 DC current gain vs. output current

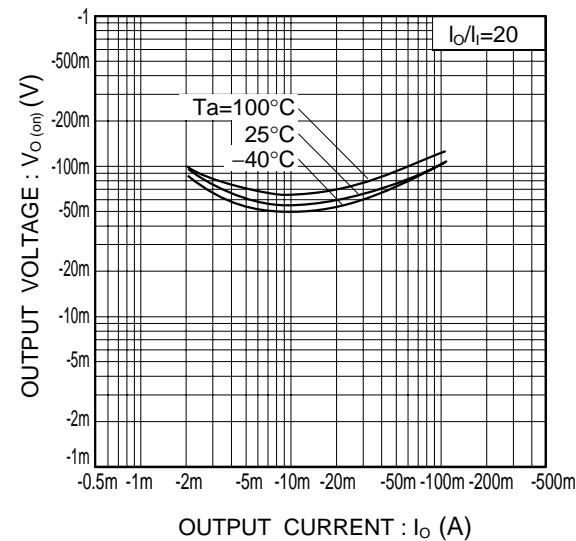
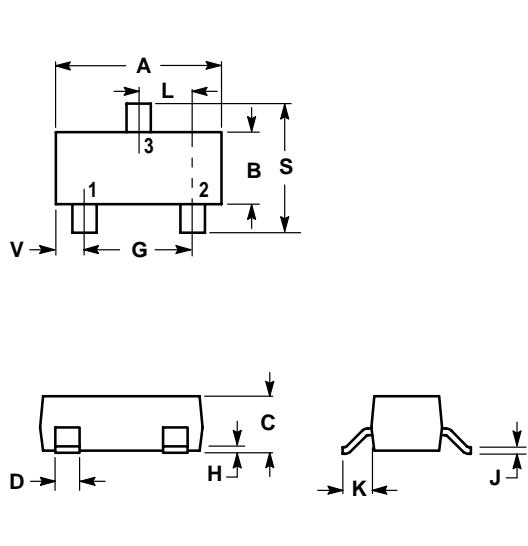


Fig.4 Output voltage vs. output current

LDTB123YLT1G,S-LDTB123YLT1G
SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

